

2.5 Gbps Multi-Mode VCSEL T056

March 2003

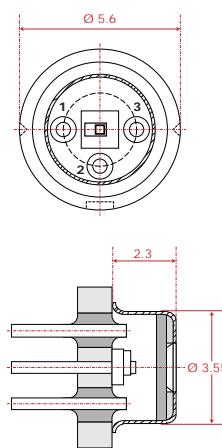


Features

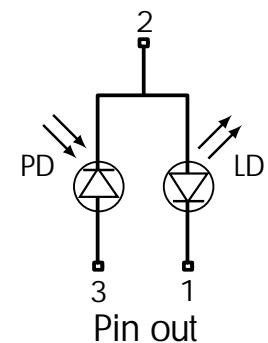
- Single VCSEL chip
- 850nm wavelength range
- Low threshold current
- Data rates up to 3.5 Gbps
- Back monitor photo diode



TO-56 window package dimension



Electrical connections



● Ordering information

Part Number APA7201011500

2.5 Gbps Multi-Mode VCSEL T056

Electro-optical characteristics

Parameter*	Symbol	Conditions	Ratings			Units
			Min	Typ	Max	
VCSEL	I_{th}		1.0	1.8	2.5	mA
	P_{out}	$I_{op} = 6 \text{ mA}$		0.7		mW
	V_{op}	$I_{op} = 6 \text{ mA}$		1.9		V
	λ	$I_{op} = 6 \text{ mA}$	840	850	860	nm
	$\Delta\lambda$	$I_{op} = 6 \text{ mA}$		0.85		nm
	η	$I_{op} = 6 \text{ mA}$	0.1	0.17	0.25	mW/mA
	θ	Full width, $1/e^2$, $I_{op} = 6 \text{ mA}$		27		°
	R_{Diff}	$I_{op} = 6 \text{ mA}$	25	45	50	Ω
	f_{3dB}	$I_{op} = 6 \text{ mA}$	3.5	5		GHz
	$RIN_{12} (\text{OMA})$	$I_{op} = 6 \text{ mA}, 1\text{GHz}$		-122		dB/Hz
Back Monitor Photo Diode	I_{dpd}	Bias = 3 V		1	30	nA
	C_{pd}	Bias = 3 V		6		pF
	BVR_{pd}		30			V
	I_{pd}	$P_{out} = 0.5 \text{ mW}$	70	200	400	μA

Thermal characteristics

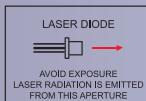
Parameter	Symbol	Ratings			Units
		Min	Typ	Max	
Temperature tuning coefficient	$\delta\lambda/\delta T$		0.06		nm/K
Threshold current variation 0 – 70°C	ΔI_{th}		0.8		mA

Absolute maximum ratings

Parameter*	Rating	Units
Optical output power	3.5	mW
Peak forward current	10	mA
VCSEL reverse voltage	5	V
PIN Photodiode reverse voltage	10	V
PIN Photodiode forward current	10	mA
Operating temperature	0 to +85	°C
Storage temperature	-40 to +100	°C
Lead solder temperature (for 10 sec.)	260	°C

*($T=25^\circ\text{C}$ unless otherwise noted)

The above specifications are subject to change without notice



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